

1.5-30MHz 100W Class A/AB High Performance Amplifier

- Class A/AB 100W XR-rated amplifier
- ❖ 1.5-30MHz bandwidth
- 52dB typical gain
- ♦ +/- 0.4dB typical gain flatness
- Temperature-compensated bias
- TTL disable
- Current sense resistor
- Available with heatsink and fan



The RFP1.5-30-100XR is a Class A/AB XR-rated amplifier, excellent as a driver or output stage in high power military, commercial, or industrial systems. Its XR rating ensures ruggedness for driving mismatched loads such as antennae or plasmas, and its high gain allows it to be driven to full power from signal generator levels. It is supplied with SMA input and output connectors.

Specifications $V_{sup} = +28VDC$, $I_{DQ} = 1.15A$, $P_{out} = 100W$, $T_{base} = 40^{\circ}C$, $Z_{load} = 50\Omega$					
Parameter	Min	Тур	Max	Units	
Freq. Range	1.5		30	MHz	
P _{1dB}	100	See Figure 4		W	
Input Power		-2	1	dBm	
Gain	49	52		dB	
Gain Flatness		+/-0.4	+/-0.8	dB	
Drain Current		7.2	7.7	Α	
Efficiency	46	50		%	
IRL		-23	-14	dB	
f ₂		-39	-28	dBc	
f ₃		-13	-10	dBc	
IMD ₃ 100W PEP, Δf=10kHz		-38	-28	dBc	
Dimensions (excluding connectors)	2.45 X 5.90 X 1.40 (62.23 X 149.86 X 35.56)			inch (mm)	

Maximum Ratings Operation beyond these ratings will void warranty.				
Parameter	Value			
V _{supply} 28V required for 100W output	24-28VDC			
Bias Current	1.5A			
Drain Current	10A			
Load Mismatch*	10:1			
Operating Baseplate Temperature	+5°C to +65°C (Non-condensing)			
Storage Temperature	-40°C to +85°C			

^{*}All phase angles, 100W forward power, current limited to 10A for 10 seconds max.

Option Ordering Info		
Heatsink and fan	RFP1.5-30-100XR- HSF	

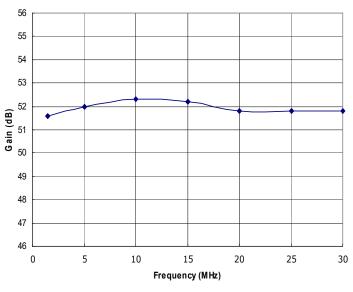
RF and Microwave Power Technology, LLC • 2380 Solitude Drive • Reno, NV 89511 USA (775) 842-3280 • sales@rfmpt.com • www.rfmpt.com

Specifications contained herein are subject to change without notice.

MADE IN AMERICA



1.5-30MHz 100W Class A/AB High Performance Amplifier

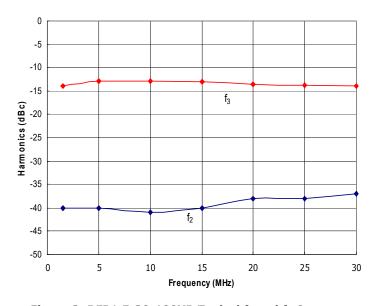


-20.0
-25.0
-30.0
-30.0
-40.0
-45.0
-50.0
0 5 10 15 20 25 30

Frequency (MHz)

Figure 1: RFP1.5-30-100XR Typical Gain @ Pout = 100W.

Figure 2: RFP1.5-30-100XR Typical IMD $_3$ @ 100W PEP, Δf =10kHz. For unbalanced IMD $_{3U}$ and IMD $_{3L}$, only the highest value is shown.



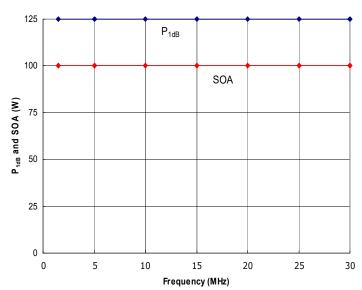


Figure 3: RFP1.5-30-100XR Typical f_2 and f_3 @ P_{out} = 100W.

Figure 4: RFP1.5-30-100XR Typical P_{1dB} and Safe Operating Area (SOA). Do not exceed the SOA without first contacting RFMPT to discuss your application.

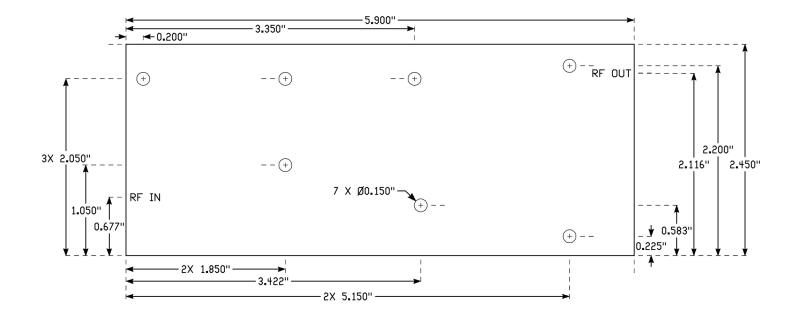
RF and Microwave Power Technology, LLC • 2380 Solitude Drive • Reno, NV 89511 USA
(775) 842-3280 • sales@rfmpt.com • www.rfmpt.com
Specifications contained herein are subject to change without notice.
RF and Microwave Power Technology, LLC assumes no liability for the use of this information.
© 2024 RF and Microwave Power Technology, LLC





1.5-30MHz 100W Class A/AB High Performance Amplifier

Amplifier Mounting Hole and RF Locations







1.5-30MHz 100W Class A/AB **High Performance Amplifier**

Instructions for Amplifier Use

- 1) If not supplied with a heatsink, apply a layer of high quality thermal grease (Wakefield Type 120 or better) to the underside of the amplifier baseplate. Thinner is better, but ensure that when mounted to your heatsink, contact across the entire baseplate is made. Gaps and air bubbles will significantly reduce cooling, leading to possible amplifier damage. Use seven #6-32 screws to mount the amplifier to your heatsink.
- 2) Guarantee sufficient airflow through the heatsink fins to keep the maximum baseplate temperature directly under the output transistor at or less than that specified in the Maximum Ratings section. Contact RFMPT for details on how to qualify your heatsink's performance, if needed.
- Connect a proper signal source to the RF IN connector, and desired load to the RF OUT connector. 3) Torque connectors to industry standards for the type supplied with the amplifier.
- Connect DC V_{supply} to the terminal provided. Solder a ground wire to the GND pad. Ensure that the 4) connections are of proper polarity, and within the voltage range in the Maximum Ratings section.
- Apply DC power, then sufficient RF drive to achieve desired output level. Ensure that the Safe 5) Operating Area (SOA) power level indicated in Figure 4 is not exceeded, or amplifier damage may occur, and will void the warranty.
- Disable is active high at 5VDC, and disables bias to the driver and output transistors. The MMIC is 6) powered anytime V_{supply} is applied to the amplifier. Due to feedback networks around both disabled stages, there will always be a very small amount of RF present at the amplifier's output whenever RF drive is present at its input.
- 7) To disconnect the amplifier, first remove the RF drive, then DC power, then the RF connections.

Contact the factory at sales@rfmpt.com with any questions, or for special options, testing requirements, and/or operating conditions not specified in this document.

Document Control

Revision	Date	Notes
Α	2-3-2019	Initial release.
В	6-6-2024	Updated performance data.

